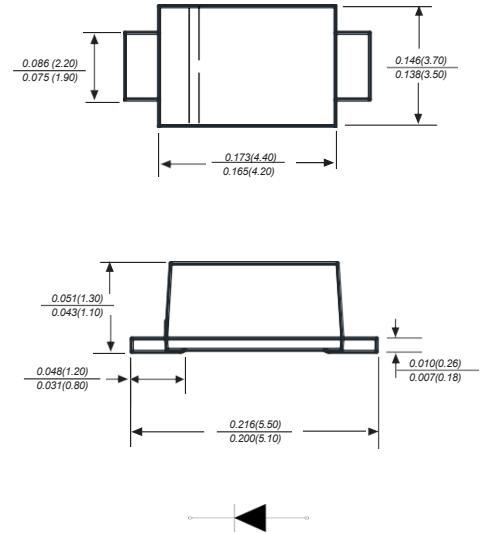


SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- ◆ Metal silicon junction,majority carrier conduction
- ◆ For surface mounted applications
- ◆ Low power loss,high efficiency
- ◆ High forward surge current capability
- ◆ For use in low voltage,high frequency inverters, free wheeling,and polarity protection applications

SMBF



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

Parameter	SYMBOLS	SL210BF	UNITS
Marking Code			
Maximum repetitive peak reverse voltage	V_{RMM}	100	V
Maximum RMS voltage	V_{RMS}	70	V
Maximum DC blocking voltage	V_{DC}	100	V
Maximum average forward rectified current at $T_L=65^\circ\text{C}$	$I_{(AV)}$	2.0	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50	A
Maximum instantaneous forward voltage at 2.0A	V_F	0.7	V
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	I_R	0.15 20.0	mA
Typical junction capacitance (NOTE 1)	C_J	100	pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	25.0	$^\circ\text{C}/\text{W}$
Operating storage temperature range	T_J	-50 to +125	$^\circ\text{C}$
Operating junction temperature range	T_{STG}	-50 to +150	$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. P.C.B. mounted with 0.5x0.5"(12.7x12.7mm) copper pad areas

Typical Characteristics

Fig.1 Forward Current Derating Curve

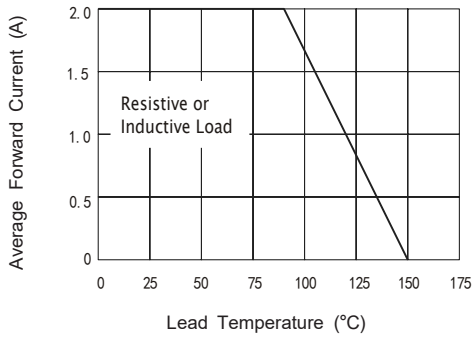


Fig.2 Typical Reverse Characteristics

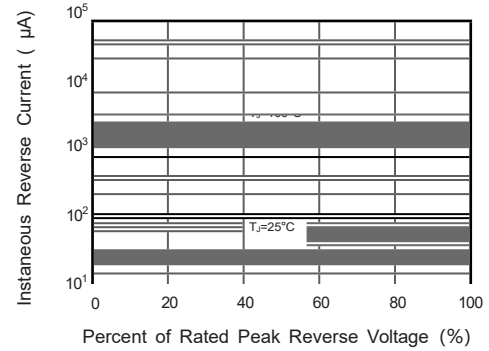


Fig.3 Typical Forward Characteristic

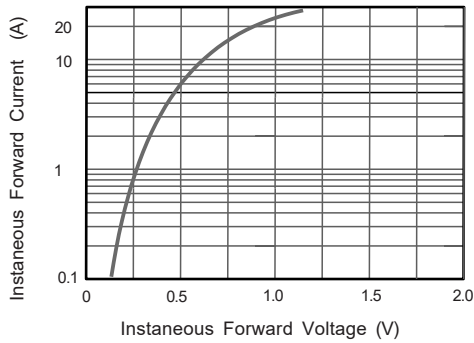


Fig.4 Typical Junction Capacitance

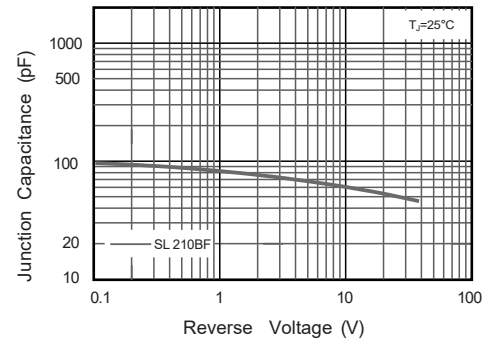


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

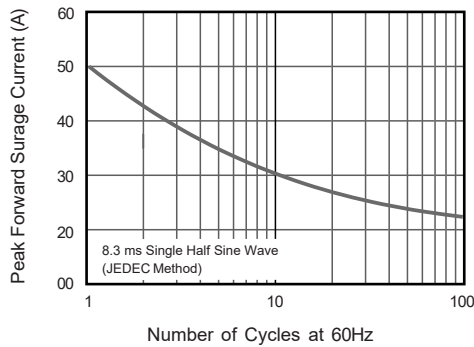
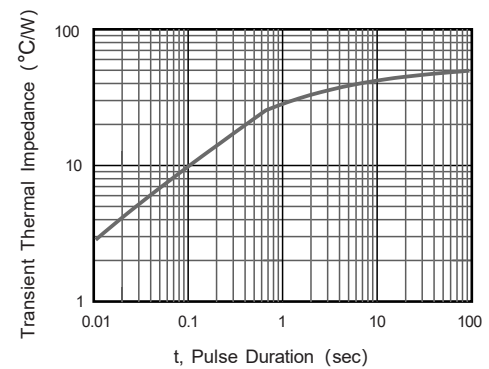


Fig.6- Typical Transient Thermal Impedance



The curve above is for reference only.